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## Acene-linked covalent organic frameworks as candidate materials for singlet fission†

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Two-dimensional covalent organic frameworks (COFs) are a versatile class of porous materials that can be tailored for solar energy conversion applications through the incorporation of organic chromophores as linker units. In this work we examine whether such COFs can be engineered to support singlet fission (SF), the generation of two triplet excitons from a single photoexcitation. We simulate the structural and electronic properties of a series of COFs possessing embedded polyacene linkers from benzene through pentacene. Detailed electronic structure calculations suggest that necessary conditions on the energy and electronic coupling for SF can be met with COF architectures closely related to those already synthetically achieved. Molecular dynamics simulations reveal that the embedded acenes preferentially adopt orientations at an angle relative to the COF plane at room temperature, modifying the energy levels and electronic couplings relative to their minimum energy conformations at 0 K. Charge mobility through the COFs is quantified as a function of the length of the embedded acene through application of a recently introduced charge transport index. Implications for the future design of porous materials supporting singlet fission are discussed.

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## 1 Introduction

Since the first covalent organic frameworks (COFs) were reported over a decade ago,<sup>1</sup> the development of COF materials for gas storage<sup>2–4</sup> and heterogeneous catalysis has blossomed due to their high surface area and porosity.<sup>5–8</sup> Although the preparation of macroscopic single crystals of COF materials remains challenging, the pace of COF development for hydrogen uptake applications has been brisk, exceeding the 2015 DOE volumetric uptake target for H<sub>2</sub> of 40 g L<sup>-1</sup> in 2012 and rapidly approaching the 2050 target.<sup>9</sup>

The porosity and ordered stacking of 2D COFs, combined with their synthetic tunability, offer important advantages for organic electronics applications. Several studies have proposed to employ electroactive COF materials, with organic chromophores embedded in the framework as linkers, as the active layer of a bulk heterojunction solar cell.<sup>10</sup> Under illumination, singlet excitons can be generated on the embedded chromophores. These sites can then act as electron donors in the presence of a suitable acceptor chromophore embedded in the COF pore<sup>10</sup> or at an adjacent linker in the framework,<sup>11,12</sup> facilitating charge separation. Furthermore, because 2D COFs with

chromophore linkers are highly ordered materials with extensive  $\pi$  conjugation and relatively short interlayer stacking distances, significant charge mobility can be achieved.<sup>13–15</sup> These investigations establish electroactive COFs as a promising platform for the development of organic solar cell materials, but the unique ordering and electronic properties of COFs suggest a further advantage that has yet to be explored.

Among the most highly desirable electronic processes to introduce into a candidate solar cell material is the phenomenon of singlet fission (SF), the creation of two triplet excitons from one singlet exciton.<sup>16,17</sup> In SF, a photoexcited organic chromophore, typically in the lowest singlet excited state S<sub>1</sub>, transfers a portion of its excitation energy to an adjacent chromophore in the ground electronic state S<sub>0</sub>, yielding a correlated

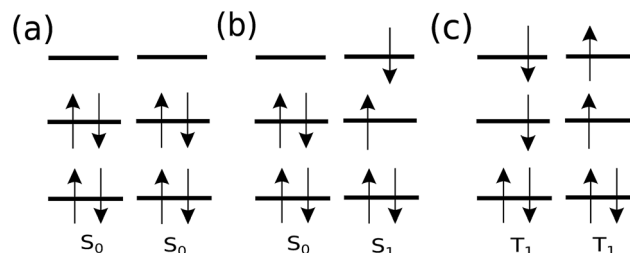


Fig. 1 Molecular orbital representation of electronic states involved in the direct mechanism for singlet fission. (a) Pair of chromophores in the S<sub>0</sub> ground state. (b) Absorption of a photon excites one chromophore to the S<sub>1</sub> excited state. (c) Energy transfer from the chromophore in the S<sub>1</sub> state to the second chromophore in the ground state produces two chromophores in the T<sub>1</sub> state.

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tolerance of  $10^{-6}$  hartree was used together with a maximum force component of  $10^{-4}$  hartree per bohr.

MD simulations were performed with the same SCC-DFTB method used for geometry optimizations due to the prohibitive computational cost of MD based on full density functional theory (DFT) applied to these extended COF systems. Our DFTB-MD simulations employ a periodically repeated four-layer unit cell of the optimized serrated-AA stacking geometries in order to reduce correlation between the motions of adjacent acenes due to periodic images. After geometry optimization and equilibration, production simulations were performed in the NVE ensemble with initial velocities corresponding to temperatures of 200 K, 300 K, and 600 K. A 1 fs time step was employed, and snapshots were collected at 40 fs intervals. The frequency distribution of linker orientations was constructed from all snapshots obtained from the four-layer simulations with the exception of the first 1 ps of MD, which was discarded in all cases.

## 2.2 Electronically excited states

We evaluate the  $S_0$ ,  $S_1$ , TT, and CT state energies of DFTB-MD snapshots using DFT calculations with the PBE0 functional and 6-311G\* basis set.<sup>43</sup> The  $S_1$  state was calculated by the  $\Delta$ SCF approach<sup>44</sup> together with the maximum-overlap method (MOM) to ensure convergence to the target state.<sup>45</sup>  $\Delta$ SCF has been benchmarked against TDDFT and experiment for the  $S_1$  state of organic dyes, including anthracene and pentacene, where  $\Delta$ PBE0 without range separation successfully reproduces the  $S_1$  excitation energy.<sup>46</sup> We employed constrained DFT (CDFT) to calculate energies and self-consistent electronic densities for the CT states.<sup>47,48</sup> CDFT has been successfully used in this context to predict singlet fission rates in tetracene and pentacene crystals.<sup>23</sup> Potential energy curves for the CT and TT states were computed by averaging over the relevant microstates; a molecular orbital scheme indicating the corresponding electron spin and charge constraints can be found in the ESI.† All DFT calculations were performed in the Q-Chem 4.3 software package.<sup>49</sup>

## 2.3 Charge mobility analysis

Charge mobility through COF layers was estimated by extracting all neighboring chromophore dimer pairs from each optimized COF model and computing the electronic coupling between one chromophore and the anion of the other within constrained DFT-based configuration interaction (CDFT-CI).<sup>48</sup> While the electronic couplings obtained from CDFT-CI should be considered qualitative, their success in predicting experimental SF rates in molecular crystals<sup>23</sup> and their best-in-class performance in recent benchmarks<sup>50</sup> support their application in our study. To retain charge balance, acene linker units extracted from the COF model were capped with hydrogens.

The computed couplings were incorporated into an adjacency matrix to evaluate the Kirchoff transport index ( $K_T$ ), a recently introduced metric which ranks the relative electron transport ability of related molecular structures.<sup>51</sup> Our approach to the evaluation of  $K_T$  closely follows the algorithm of ref. 51.

To break the high translational symmetry of the optimized COF structures and explore the effect of disorder on charge mobility, we applied the coupling estimation scheme above to snapshots from the DFTB-MD simulations. Electronic couplings from 100 snapshots per structure were aggregated to find average couplings between acene units for the Kirchoff transport index analysis.

# 3 Results and discussion

## 3.1 Stacking energies and patterns

X-ray diffraction (XRD) patterns of many 2D COFs have revealed a general preference for AA or slipped-AA stacking over AB stacking.<sup>52</sup> The typically broad nature of the XRD peaks indicate that lower-symmetry slipped stacking orientations are most prevalent.<sup>42,53</sup> Variations in the COF stacking pattern affect the relative orientations of the embedded acenes, thereby influencing the energies, electronic couplings, and ultimately the rate of SF. To account for this orientation dependence, the four stacking patterns commonly observed in 2D COFs were investigated to determine the preferred stacking of these acene-linked COFs. Optimized structures for the stacking patterns considered in this study were calculated using SCC-DFTB<sup>41</sup> and are depicted in Fig. 3.

The binding energy for each stacking configuration was determined by subtracting twice the total energy of an isolated monolayer from that of a periodically repeated two-layer unit cell. The binding energies (Table 1) show that serrated AA stacking is slightly preferred over inclined and AA stacking, all of which are more stable than AB stacking. The order of stacking preference is mirrored in the optimized interlayer distances (ESI Table S1†), with the lowest energy structures corresponding to the smallest interlayer distances.

Our finding that slipped stacking is preferred to cofacial AA stacking is consistent with recent nonadiabatic fewest-switches surface hopping (FSSH) simulations of pentacene dimers.<sup>33</sup> Furthermore, investigations of SF in perfluoropentacene have shown that SF is enhanced by slip stacking, whereas a perfectly

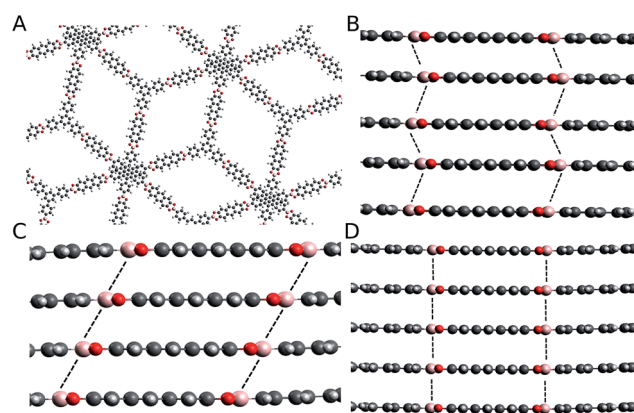


Fig. 3 Molecular representation of the stacking patterns investigated in this study: (A) AB (B) serrated AA (C) inclined AA (D) perfect AA stacking.



**Table 1** Binding energies of four stacking for acene containing COFs. All energies are in kcal mol<sup>-1</sup>

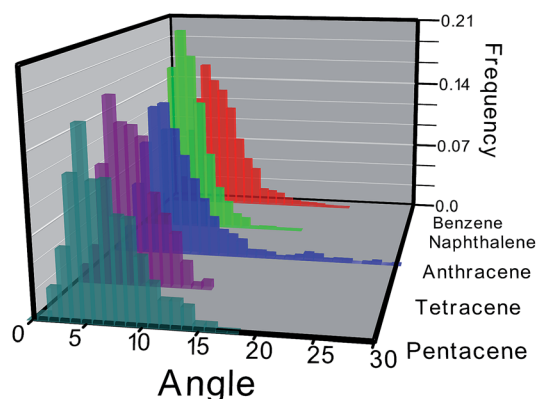
Acene unit	AB	Serrated AA	Inclined AA	AA
Benzene	-40.00	-100.55	-98.64	-96.68
Naphthalene	-42.12	-116.72	-115.81	-112.06
Anthracene	-43.85	-133.07	-132.26	-127.54
Tetracene	-46.01	-148.53	-147.99	-142.80
Pentacene	-48.73	-164.42	-163.76	-158.12

eclipsed orientation suppresses the mechanism.<sup>32</sup> Thus the apparent preference for slip stacking in acene-linked COFs supports their potential as candidate frameworks for materials supporting SF.

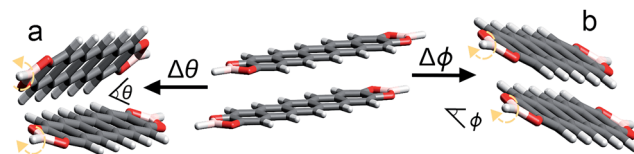
### 3.2 Framework flexibility at room temperature

To account for the possibility that flexibility in the COF structure might affect electronic energies and couplings at device operating temperatures, *i.e.* at room temperature, we used molecular dynamics (MD) simulations to sample commonly adopted COF configurations. In these multilayer room temperature MD simulations, the acene units within the COF adopt an unexpectedly wide distribution of orientations relative to the COF plane. Surprisingly, the observed distribution of angles was effectively independent of acene length (Fig. 4).

At 300 K, angles between 5 and 10° were most common, and the angular distributions show only a small skew toward larger angles. At 200 K, the distributions are narrower and favor orientations closer, on average, to planar (0°). At 600 K, the increased thermal energy enhances fluctuations in the orientation of the acene unit relative to the COF plane. This creates a much broader distribution with the most frequent angle occurring at 10° and with this key angle regularly exceeding 20°. Vertically adjacent acene units remain mostly co-planar, but herringbone-like orientations occur as well. This fluctuation in the relative angle of the embedded acene units can impact the energy and coupling between adjacent acenes; the rate of SF is highly sensitive to both of these factors.



**Fig. 4** Acene unit angle distribution observed in molecular dynamics simulations at 300 K.



**Fig. 5** Rotation of capped acene segments from a slip-stacked planar position (middle). (a) Rotation of a pair of segments to a herringbone orientation. The angle  $\theta$  is the internal angle the segments make with one another. (b) Rotation of a pair of segments, which remain coplanar, relative to the COF plane. The angle  $\phi$  is the angle either acene makes with the COF plane.

### 3.3 Electronic energies relative to SF criteria

As the orientations of nearby acenes in adjacent layers fluctuate, the relative energies of the ground and low-lying excited states of the acene-COFs may also vary. To determine which configurations are most favorable for SF, we calculated the energies of the first singlet excited state ( $S_1$ ), the lowest charge-transfer (CT) states, and the triplet-pair state (TT) from Fig. 1 along two orientational degrees of freedom. The first degree of freedom  $\theta$  is an out-of-plane rotation of one acene unit relative to the other, connecting co-planar and herringbone conformations (Fig. 5a). The second degree of freedom  $\phi$  is a collective rotation of both acenes relative to the rest of the COF (Fig. 5b). The acenes remain co-planar along the second degree of freedom, but the effective distance and degree of slip-stacking between the acene varies. These calculations are performed on borate-capped acenes extracted from the full COF structures for computational tractability with CDFT-CI. Excitation energies from  $S_0$  to each state are shown in Fig. 6 for tetracene and pentacene; analogous results for smaller acenes are available in the ESI.†

Up to 40° from co-planarity, we observe only small changes in the  $S_0$ -CT and  $S_0$ -TT energy gaps with respect to  $\theta$  (Fig. 6a and b) and a modest decrease in the  $S_0$ - $S_1$  energy gap. Along  $\phi$ , there is a steeper decrease in all three energy gaps between 30° and 40°, especially for the  $S_1$  state (Fig. 6c and d). As  $\phi$  increases, the effective distance between the acene units decreases, giving rise to steric effects that may partially explain the trend as a destabilization of  $S_0$  relative to the excited states. At the same time, the relative phase of the acene frontier orbitals changes with  $\phi$ ; such phase shifts can significantly alter electronic energies and couplings.<sup>54</sup> However, such large values of  $\phi$  are not commonly observed at room temperature (Fig. 4). The orbital phase change should have the greatest impact on the CT state because the dominant donor and acceptor orbitals for this state are on different acenes. Given that the observed decrease is independent of the particular acene or electronic state in question, we attribute the change in  $S_1$  excitation energy along  $\phi$  primarily to the changing effective distance between adjacent acenes.

Excitation energies for the  $S_1$ , CT, and TT states all decrease with increasing acene length, in keeping with the known properties of their isolated chromophore equivalents and with the particle-in-a-box model of electronic excitations in quasi-1D systems. Although the energies of all states considered here





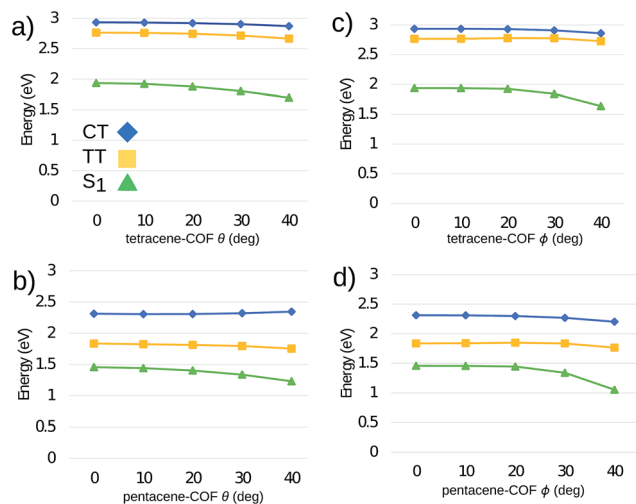


Fig. 6 Excitation energies from  $S_0$  to the  $S_1$ , CT, and TT states for capped acene dimers along rotational degrees of freedom described by the angles  $\theta$  and  $\phi$  introduced in Fig. 5.

decrease with increasing acene length, the decrease in the  $S_0$ -TT energy gap as a function of acene length is more drastic than that of the  $S_0$ - $S_1$  energy gap. Critically, the energy difference between the  $S_1$  state and the TT state falls from 3.7 eV in the benzene-COF to less than 0.4 eV in the pentacene-COF. The energy level criterion for SF is approximately met when these two levels become nearly degenerate. These results indicate that the pentacene-embedded COF comes close to meeting a key condition for SF in its optimized geometric structure and has the highest likelihood, among the structures investigated here, of adopting configurations favorable to SF.

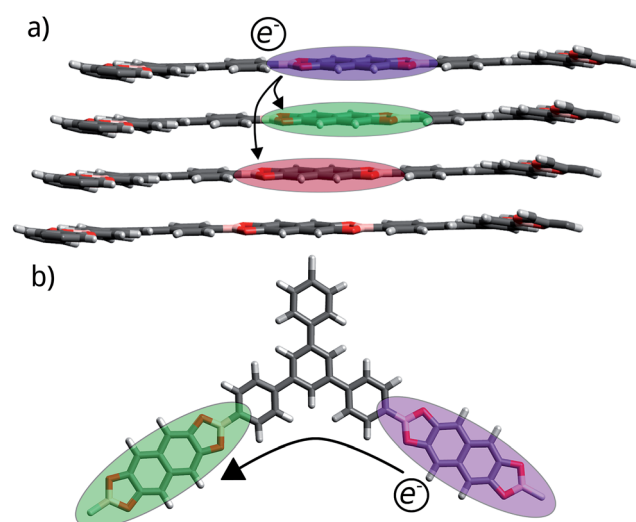


Fig. 7 Schematic of charge mobility through acene-COFs. (a) Vertical mobility depicting the transfer of an electron one segment away (purple to green) and two segments away (purple to red). (b) Horizontal mobility depicting the transfer of an electron one segment away (purple to green).

### 3.4 Electron mobility along slip-stacked COF layers

For acene-COFs to be viable candidates for the active layer of a bulk heterojunction solar cell, it is not only enough to generate excitons and electron-hole pairs in sufficient quantity. These COFs must also demonstrate sufficient electron and hole mobility to deliver charge carriers to the electrodes. In the case of ordered 2D COFs, in order to utilize the energy captured by the embedded chromophores, electrons must be readily transported across the COF layers, as illustrated schematically in Fig. 7.

It has been demonstrated that certain electroactive COFs can achieve high electron mobilities.<sup>37</sup> Tetrathiafulvalene-based COFs can achieve conductivity on the order of  $10^{-5}$  to  $10^{-6} \Omega^{-1} \text{cm}^{-1}$  due to their highly ordered  $\pi$ -stacking structure.<sup>14</sup> To estimate the relative mobility of our acene-COFs, we implemented and applied a recently developed measurement tool called the Kirchoff transport index.<sup>51</sup> This approach to the characterization of electron mobility in organic materials treats the conduction of electrons among available sites by analogy to classical resistor network theory.

The Kirchoff transport index is not an absolute measure of electron mobility in  $\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$ ; instead, it provides a relative measure of transport that can be used to compare the electron mobility of related materials. Nevertheless, for a rough estimate of the electron mobility in these acene-COFs, one can compare the  $K_T$  values obtained in this study against the values of approx. 100 meV obtained for PC<sub>60</sub>BM in ref. 51, which correspond to an electron mobility of  $5 \times 10^{-2} \text{cm}^2 \text{V}^{-1} \text{s}^{-1}$ .<sup>55</sup> By constructing an adjacency matrix from electronic couplings between adjacent neutral and anion electronic states *via* CDFT-CI, we evaluated the Kirchoff transport index  $K_T$  for vertical and horizontal electron transport in each of the acene-COFs investigated here.

Relative charge mobilities for the acene-COFs are reported in Table 2. Charge mobility was assessed between adjacent COF planes (vertical) as well as across acenes within the same plane (horizontal). Consistent with the interrupted nature of the  $\pi$  conjugation between adjacent acenes within the same plane, the horizontal mobility is predicted to be smaller than the vertical mobility between planes. This preferential mobility along the stacking direction is consistent with other investigations of conductive COFs.<sup>14</sup> While the coupling is strongest between adjacent acenes, a small interaction is also seen between acenes two layers away, with the effect dropping below any meaningful magnitude beyond two layers. The deviation from the trend of decreasing  $K_T$  with increasing acene length observed in naphthalene was traced back to a slightly larger-

Table 2 Kirchoff transport indices for vertical and horizontal charge mobility in optimized acene-COFs. All reported values are in meV

Acene unit	Vertical $K_T$	Horizontal $K_T$
Benzene	101.401	32.932
Naphthalene	14.170	17.688
Anthracene	81.480	7.746
Tetracene	74.022	4.740
Pentacene	43.903	4.150



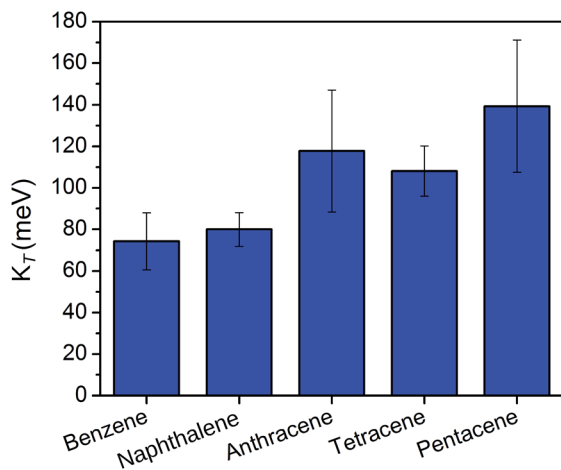


Fig. 8 Kirchoff index ( $K_T$ ) values in meV calculated for various acene-COFs at 300 K. Error bars indicate standard deviations in  $K_T$  across MD snapshots.

than-expected optimized interlayer spacing, reflecting the fact that electronic couplings between distant molecular fragments can be exponentially sensitive to distance.

Snapshots from the previously detailed MD simulations were used to gain insight into the fluctuations of  $K_T$  with structure at room temperature. The observed distributions of  $K_T$  are illustrated in Fig. 8. In contrast to the optimized slip-stacked geometries at 0 K, the value of  $K_T$  increases with acene length at finite temperature. With an average value of 74 meV for the benzene containing COF and 139 meV for the pentacene containing COF, charge mobility for the pentacene-linked COF is estimated to be almost double that of the benzene-linked COF at operating temperatures. The sharply contrasting trends between the predicted electron mobilities in the static *versus* dynamic analyses illustrates the high sensitivity of electronic coupling to molecular orientation in organic semiconductors and the importance of configurational sampling in predicting electronic properties like the charge carrier mobility.

## 4 Conclusions

In summary, we have investigated the electronic properties of experimentally realizable 2D COFs with embedded acene linkers to determine their capacity to support singlet fission. We found that the embedding of acenes within the COF does not significantly perturb the energy levels of the  $S_1$  and triplet-pair (TT) excited states of the embedded acenes. This finding offers preliminary evidence that monomer properties are indeed meaningful for the design of COFs capable of supporting SF. Consequently, our study suggests that the search for COFs capable of SF can rely heavily on the underlying electronic properties of their embedded organic chromophore dimers, greatly simplifying both computational and experimental screening efforts.

The acene-COF materials examined here prefer to adopt a slip-stacked orientation which is known to be beneficial for SF. Molecular dynamics simulations revealed that the acene

units can adopt a distribution of angles that appears to be independent of acene length but that broadens with increased temperature. From the construction of potential energy curves along two key orientational degrees of freedom, we showed that pentacene-embedded COFs can satisfy the energetic requirements for SF at orientations achieved at room temperature. This finding is especially ripe for future experimental validation or refutation.

From analysis of the charge mobility by the Kirchoff transport index, we found that increasing the length of the embedded acene unit from benzene to pentacene significantly increases mobility along the stacking direction. By embedding a longer acene into the COF, the energy requirements for SF are more closely met with the added benefit of increased charge mobility when compared to those with smaller embedded acenes.

This investigation suggests several avenues for future work. Given that the pentacene-embedded COFs best matched the energy level criteria for SF, one may consider whether even longer embedded acenes may offer better energetics, provided that a viable synthetic route to such COFs could be identified. This study considered one specific COF-linker chemistry, but there exist a number of alternative strategies which would result in analogous acene-COFs with different stacking patterns and energetics. Thus there already exist several known routes to closely related structures which may be even better-suited to SF than the family of acene-COFs studied here. Beyond these alternative linker chemistries, it is interesting to consider the wide range of options available for fine-tuning the embedded chromophore's electronic structure for SF;<sup>56</sup> for example, one may adjust the interlayer stacking distances or even restrict the chromophore's orientational degrees of freedom through bulky substituents or by silicon substitution within the chromophore.<sup>57</sup> This investigation lays the foundation for computational screening towards the experimental realization of electroactive COFs as SF materials.

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